Bipolar Transistors Silicon PNP/NPN Epitaxial Type (PCT Process)(Bias Resistor built-in Transistor)

# **RN4910FE**

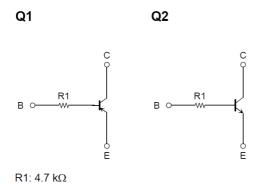
#### 1. Applications

- Switching
- Inverter Circuits
- Interfacing
- Driver Circuits

#### 2. Features

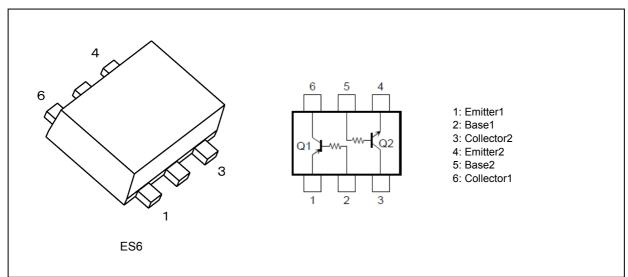
- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) Small package (Dual type)
- (3) The integrated bias resistor reduces the number of external parts required, making it possible to reduce system size and assembly time.

#### 3. Equivalent Circuit



(Q1, Q2 common)

#### 4. Packaging and Pin Assignment



#### 5. Orderable part number

Orderable part number	AEC-Q101		Note		
RN4910FE,LF	— General Use		General Use		
RN4910FE,LXGF	YES	(Note 1)	Unintended Use (Note		
RN4910FE,LXHF	YES		Automotive Use		

Note 1: For more information, please contact our sales or use the inquiry form on our website.

#### 6. Q1 Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	
Emitter-base voltage	V <sub>EBO</sub>	-5	
Collector current	Ι <sub>C</sub>	-100	mA

#### 7. Q2 Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	50	V
Collector-emitter voltage	V <sub>CEO</sub>	50	
Emitter-base voltage	V <sub>EBO</sub>	5	
Collector current	Ι <sub>C</sub>	100	mA

#### 8. Q1, Q2 Common Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteri	Symbol	Rating	Unit	
Collector power dissipation	(Note 1)	P <sub>C</sub>	100	mW
Junction temperature		Тj	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

#### 9. Q1 Electrical Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -50 V, I <sub>E</sub> = 0 mA	_	_	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -5 V, I <sub>C</sub> = 0 mA	_		-100	
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -1 mA	120		400	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = -5 mA, I <sub>B</sub> = -0.25 mA	_	-0.1	-0.3	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -10 V, I <sub>C</sub> = -5 mA	_	200	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0 mA, f = 1 MHz		3	6	pF

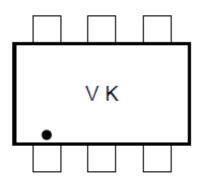
### 10. Q2 Electrical Characteristics (Unless otherwise specified, $T_a$ = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0 mA	_		100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0 mA	_	_	100	
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	120		700	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 5 mA, I <sub>B</sub> = 0.25 mA	_	0.1	0.3	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5 mA	_	250	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0 mA, f = 1 MHz		3	6	pF

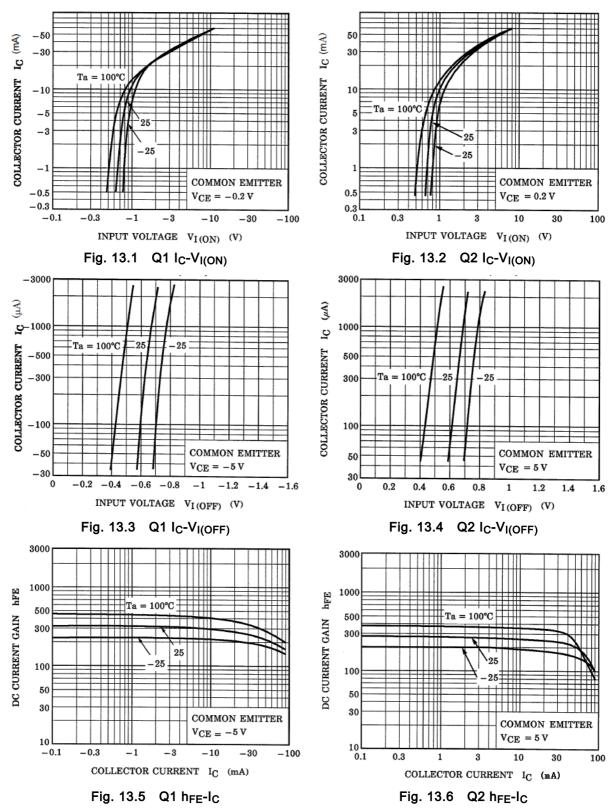
### 11. Q1, Q2 Common Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input resistance	R <sub>1</sub>	-	3.29	4.7	6.11	kΩ

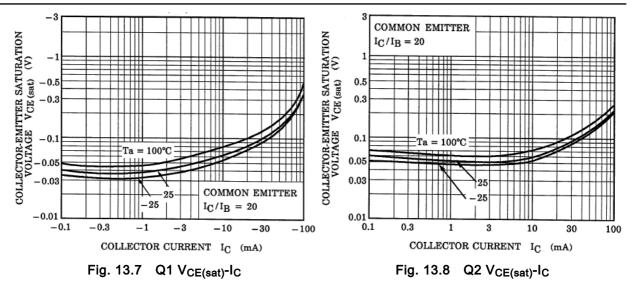
#### 12. Marking



#### 13. Characteristics Curves (Note)





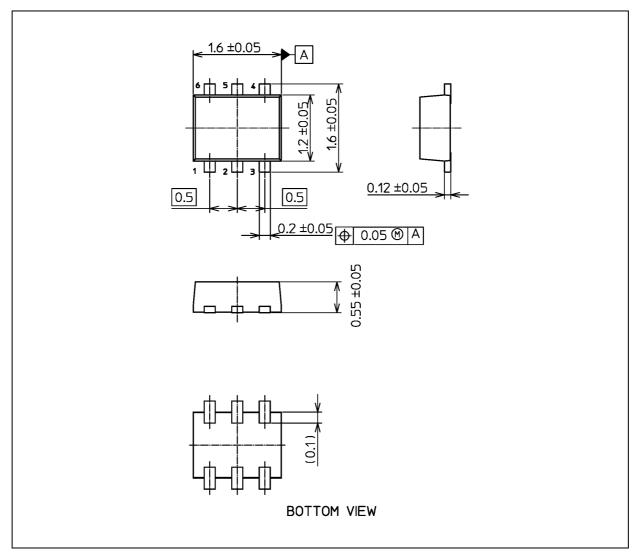


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



#### Package Dimensions

Unit: mm



Weight: 3.0 mg (typ.)

	Package Name(s)
TOSHIBA: 1-2X1S	
Nickname: ES6	

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